Rochester Electronics

Datasheet

PART NUMBER

TL514CN-ROCV

Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All re-creations are done with the approval of the Original Component Manufacturer. (OCM)

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceeds the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-38535
    - Class Q Military
    - Class V Space Level

Qualified Suppliers List of Distributors (QSLD)

- Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OCM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.

D999, OCTOBER 1977–REVISED MARCH 1988

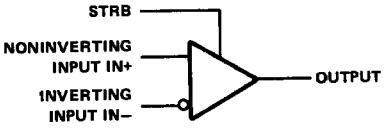
- **Fast Response Times**
- **High Differential Voltage Amplification**
- **Low Offset Characteristics**
- **Outputs Compatible with Most TTL Circuits**

description

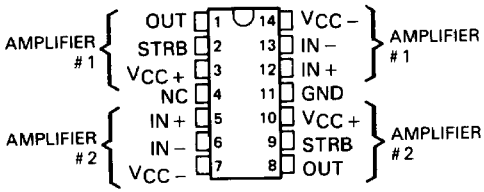
The TL514 is an improved version of the TL720 dual high-speed voltage comparator. When compared with the TL720, these circuits feature higher amplification (typically 33,000) due to an extra amplification stage, increased accuracy because of lower offset characteristics, and greater flexibility with the addition of a strobe to each comparator. Since the output cannot be more positive than the strobe, a low-level input at the strobe will cause the output to go low regardless of the differential input.

These circuits are especially useful in applications requiring an amplitude discriminator, memory sense amplifier, or a high-speed limit detector. The TL514M is characterized for operation over the full military temperature range of −55°C to 125°C.

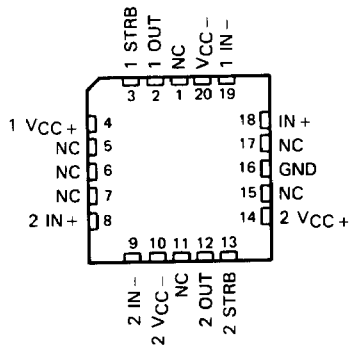
symbol (each comparator)



J OR W PACKAGE
(TOP VIEW)

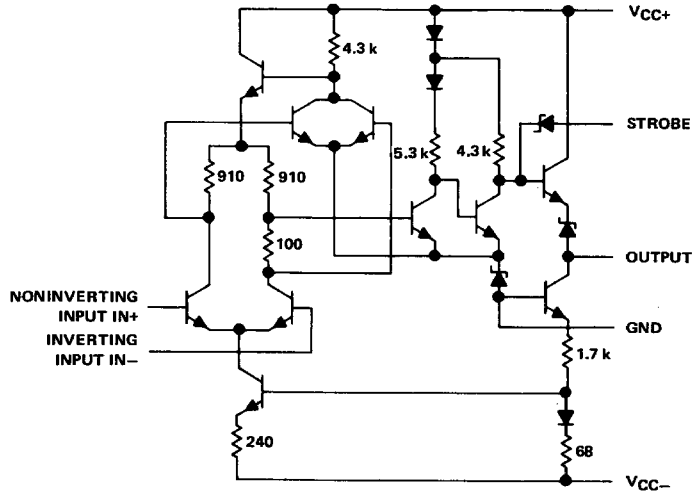


FK CHIP CARRIER
(TOP VIEW)



NC – No internal connection

schematic (each comparator)



Resistor values shown are nominal in ohms.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage V_{CC+} (see Note 1) . . . . . 14 V
Supply voltage V_{CC-} (see Note 1) . . . . . −7 V
Differential input voltage (see Note 2) . . . . . ±5 V
Input voltage (any input, see Note 1) . . . . . ±7 V
Strobe voltage (see Note 1) . . . . . 6 V
Peak output current ($t_w \leq 1$ s) . . . . . 10 mA
Continuous total dissipation (either comparator or both together) . . . . . See Dissipation Rating Table
Operating free-air temperature range . . . . . −55°C to 125°C
Storage temperature range . . . . . −65°C to 150°C
Case temperature for 60 seconds: FK package . . . . . 260°C
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds: J or W package . . . . . 300°C

NOTES: 1. All voltage values, except differential voltages, are with respect to the network ground terminal.
2. Differential voltages are at the noninverting input terminal with respect to the inverting input terminal.

DISSIPATION RATING TABLE

PACKAGE	$T_A \leq 25°C$ POWER RATING	DERATING FACTOR	DERATE ABOVE T_A	$T_A = 125°C$ POWER RATING
FK	600 mW	11.0 mW/°C	95°C	275 mW
J	600 mW	11.0 mW/°C	95°C	275 mW
W	600 mW	8.0 mW/°C	75°C	200 mW

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electrical characteristics at specified free-air temperature, V_{CC+} = 12 V, V_{CC-} = −6 V

PARAMETER		TEST CONDITIONS†		MIN	TYP	MAX	UNIT
V_{IO}	Input offset voltage	$R_S \le 20\ \Omega$, See Note 4	25°C		0.6	2	mV
			−55°C to 125°C			3	
α_{VIO}	Average temperature coefficient of input offset voltage	R_S = 50 Ω, See Note 4	−55°C to 25°C		3	10	μV/°C
			25°C to 125°C		3	10	
I_{IO}	Input offset current	See Note 4	25°C		0.75	3	μA
			−55°C		1.8	7	
			125°C		0.25	3	
α_{IIO}	Average temperature coefficient of input offset current	See Note 4	−55°C to 25°C		15	75	nA/°C
			25°C to 125°C		5	25	
I_{IB}	Input bias current	See Note 4	25°C		7	15	μA
			−55°C		12	25	
$I_{IH(S)}$	High-level strobe current	$V_{(strobe)}$ = 5 V, V_{ID} = −5 mV	25°C			±100	μA
$I_{IL(S)}$	Low-level strobe current	$V_{(strobe)}$ = −100 mV, V_{ID} = 5 mV	25°C		−1	−2.5	mA
V_{ICR}	Common-mode input voltage range	V_{CC} = −7 V	−55°C to 125°C	±5			V
V_{ID}	Differential input voltage range		−55°C to 125°C	±5			V
A_{VD}	Large-signal differential voltage amplification	No load, V_O = 0 to 2.5 V	25°C	12.5	33		V/mV
			−55°C to 125°C	10			
V_{OH}	High-level output voltage	V_{ID} = 5 mV, I_{OH} = 0	−55°C to 125°C		4§	5	V
		V_{ID} = 5 mV, I_{OH} = −5 mA	−55°C to 125°C	2.5	3.6§		
V_{OL}	Low-level output voltage	V_{ID} = −5 mV, I_{OL} = 0	−55°C to 125°C	−1	−0.5§	0‡	V
		$V_{(strobe)}$ = 0.3 V, V_{ID} = 5 mV, I_{OL} = 0	−55°C to 125°C	−1		0‡	V
I_{OL}	Low-level output current	V_{ID} = −5 mV, V_O = 0	25°C	2	2.4		mA
			−55°C	1	2.3		
			125°C	0.5	2.3		
r_o	Output resistance	V_O = 1.4 V	25°C		200		Ω
CMRR	Common-mode rejection ratio	$R_S \le 200\ \Omega$	−55°C to 125°C	80	100§		dB
I_{CC+}	Supply current from V_{CC+}¶	V_{ID} = −5 mV, No load	−55°C to 125°C		11§	18	mA
I_{CC-}	Supply current from V_{CC-}¶		−55°C to 125°C		−7§	−14	mA
P_D	Total power dissipation¶		−55°C to 125°C		180§	300	mW

† Unless otherwise noted, all characteristics are measured with the strobe open.

‡ The algebraic convention, where the most-positive (least-negative) limit is designated as maximum, is used in this data sheet for logic levels only, e.g., when 0 V is the maximum, the minimum limit is a more-negative voltage.

§ These typical values are at T_A = 25°C.

¶ Supply current and power dissipation limits apply for both comparators operating simultaneously.

NOTE 4: These characteristics are verified by measurements at the following temperatures and output voltage levels: V_O = 1.8 V at T_A = −55°C, V_O = 1.4 V at T_A = 25°C, and V_O = 1 V at T_A = 125°C. These output voltage levels were selected to approximate the logic threshold voltages of the types of digital logic circuits this comparator is intended to drive.

switching characteristics, V_{CC+} = 12 V, V_{CC-} = −6 V, T_A = 25°C

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Response time	$R_L = \infty$ C_L = 5 pF, See Note 5		30	80	ns
Strobe release time	$R_L = \infty$ C_L = 5 pF, See Note 6		5	25	ns

NOTES: 5. The response time specified is for a 100-mV input step with 5-mV overdrive.
6. For testing purposes, the input bias conditions are selected to produce an output voltage of 1.4 V. A 5-mV overdrive is then added to the input bias voltage to produce an output voltage which rises above 1.4 V. The time interval is measured from the 50% point of the strobe voltage curve to the point where the overdriven output voltage crosses the 1.4-V level.

TYPICAL CHARACTERISTICS

LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION vs FREE-AIR TEMPERATURE

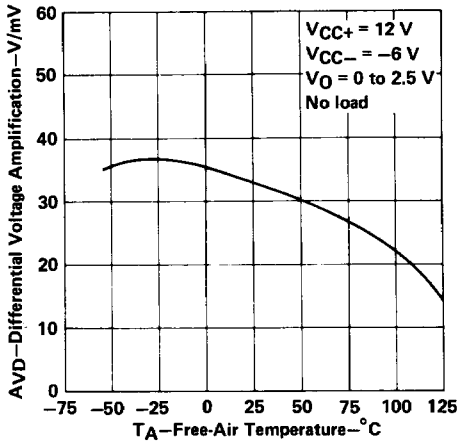

FIGURE 1

LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION vs SUPPLY VOLTAGE

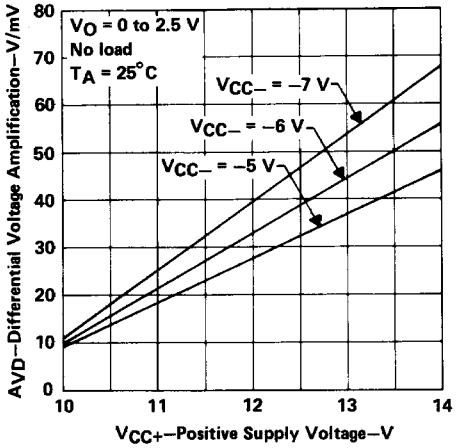

FIGURE 2

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TYPICAL CHARACTERISTICS

OUTPUT VOLTAGE LEVELS
vs
FREE-AIR TEMPERATURE

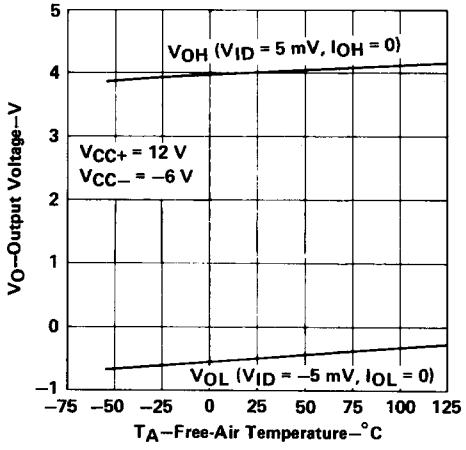

FIGURE 3

LOW-LEVEL OUTPUT CURRENT
vs
FREE-AIR TEMPERATURE

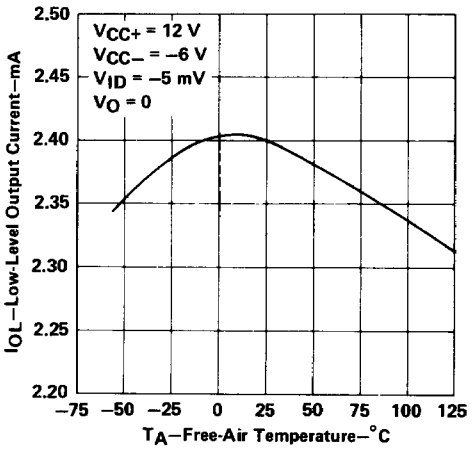

FIGURE 4

VOLTAGE TRANSFER CHARACTERISTICS

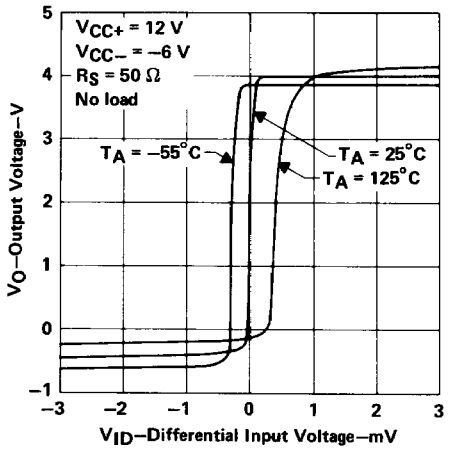

FIGURE 5

3 Voltage Comparators

TYPICAL CHARACTERISTICS

INPUT BIAS CURRENT
vs
FREE-AIR TEMPERATURE

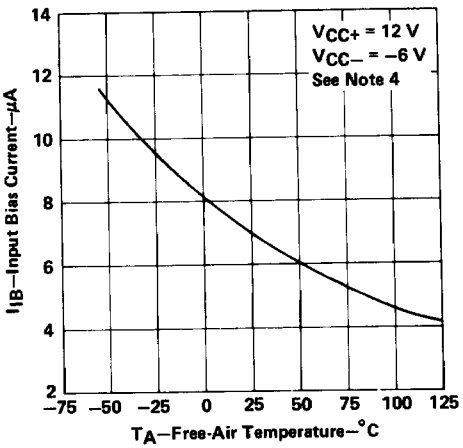

FIGURE 6

COMMON-MODE REJECTION RATIO
vs
FREE-AIR TEMPERATURE

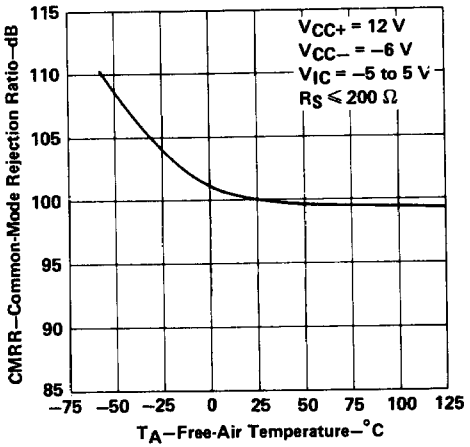

FIGURE 7

OUTPUT RESPONSE FOR
VARIOUS INPUT OVERDRIVES

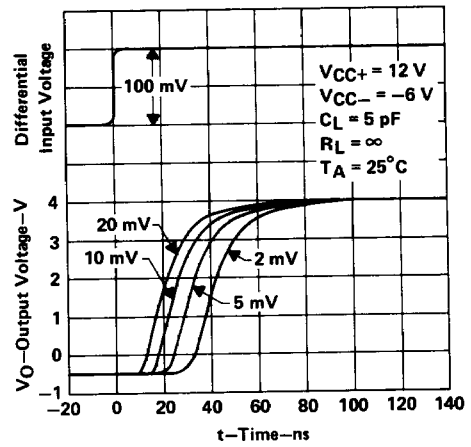

FIGURE 8

STROBE RELEASE TIME
FOR VARIOUS INPUT OVERDRIVES

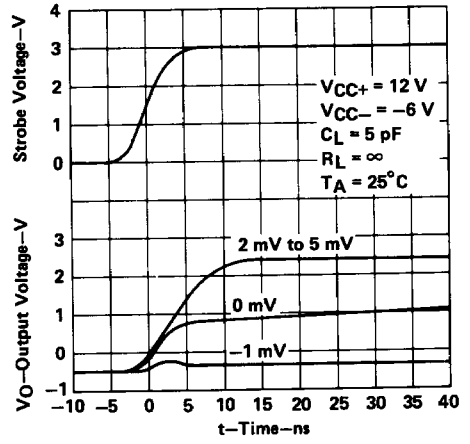

FIGURE 9

NOTE 4: These characteristics are verified by measurements at the following temperatures and output voltage levels: V_O = 1.8 V at T_A = −55°C, V_O = 1.4 V at T_A = 25°C, and V_O = 1 V at T_A = 125°C. These output voltage levels were selected to approximate the logic threshold voltages of the types of digital logic circuits this comparator is intended to drive.

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TYPICAL CHARACTERISTICS

COMMON-MODE PULSE RESPONSE

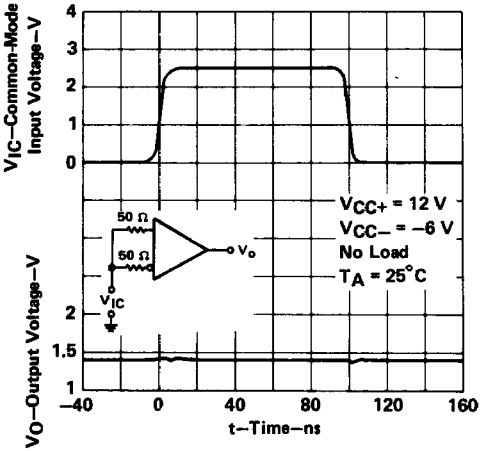

FIGURE 10

TOTAL POWER DISSIPATION
vs
FREE-AIR TEMPERATURE

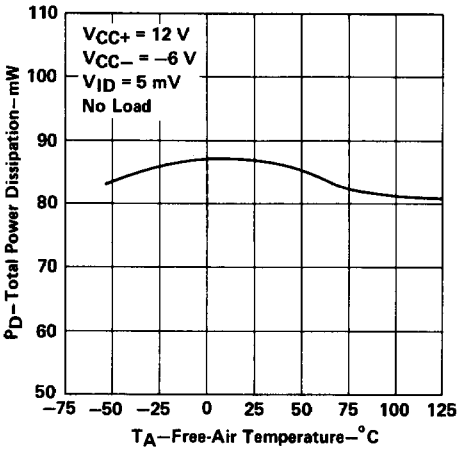

FIGURE 11